



## **SCR's 1-70 AMPS**

NON-SENSITIVE GATE

## **General Information**

The Teccor Electronics line of thyristor SCR semiconductors are half-wave unidirectional gate-controlled rectifiers which complement Teccor's line of sensitive gate SCR's. Teccor offers devices with current ratings from 1-70 Amps and Voltage ratings from 30-600 Volts with gate sensitivities from 10-50 milliamps. If gate currents in the 1-500 microamp ranges are required, please consult Teccor's sensitive gate SCR technical data sheets.

## **Electrically Isolated Packages**

Teccor's SCR's are available in a choice of 8 different device packages. Four of the 8 packages are offered in electrically isolated construction where the case or tab is internally isolated to allow

the use of low cost assembly and convenient packaging techniques.

The Teccor line of SCR's features glass passivated device junctions to insure long term device reliability and parameter stability. Teccor's glass offers a rugged, reliable barrier against junction contamination.

## **Features**

- Electrically Isolated Packages
- High Voltage Capability 30-600 Volts
- High Surge Capability up to 950 Amps
- Glass Passivated Chip

<u> </u>	Part Number					1	<del></del>	V			F .	., .	<del></del>	,	l		г
	Isol	ated P	art Numb	<b>er</b> Non-Isolated	<u> </u>	1	Ť	VDRM & VRRM	10	iT*	IDR	M & IF	RRM	VTM	V(	<b>GT</b>	
TYPE	K	O	O A K G	O A	·A O K	On-{ Cur (1)	imum State rent (2)	Repetitive Peak Off-State Forward & Reverse Voltage	Gate-1 Cur VD = RL =	C Frigger rent 12 VDC : 60Ω (12)	Fors	eak Off-Sta ward & Rev Current @ DRM & VRF	erse	Peak On-State Voltage at Max Rated RMS Current TC = 25°C (3)	VD = RL = (8)	tage 12 VDC	
	10-92	TO-220AB	A TO-202AB	G TO-202AB	NON-ISOLATED TO-220AB	it(RMS)	I <sub>T(AV)</sub>	Volts	n	ıA	T <sub>C =</sub> 25°C	TC = 100°C	T <sub>C =</sub> 125°C	Volts	T <sub>C =</sub> 25°C	T <sub>C =</sub> 125°C	
	FOR DIME	NSIONAL OUTLI	NES & PACKAGE	VARIATIONS S	EE PAGE 67	MAX	MAX	MIN	MIN	MAX	١	MAXIMUN	1	MAX	MAX	MIN	
	\$031E					1.0	0.64	30	1	10	.01	0.2	0.5	1.6	1.5	0.2	
ĺ	\$051E			,		1.0	0.64	50	1	10	.01	0,2	0.5	1.6	1.5	0.2	
_1	\$101E		<u> </u>			1.0	0.64	100	1	10	,01	0.2	0.5	1.6	1.5	0.2	<u> </u>
Amp	\$201E	<u> </u>	<u> </u>			1.0	0.64	200	1	10	.01	0.2	0.5	1.6	1.5	0.2	ļ
-	\$401E			·		1.0	0.64	400	1	10	.01	0.2	0.5	1,6	1.5	0.2	
	S601E	603041	<b>!</b>	ļ	<del> </del>	1.0	0.64	600	1	10	.01	0.2	0.5	1.6	1.5	0.2	<u> </u>
		S0301L S0501L	<del> </del>		<u> </u>	1.6 1.6	1.0 1.0	30 50	1	10 10	.01 .01	0.2	0.5 0.5	1.6 1.6	1.5 1.5	0.2 0.2	ļ
1.6	<del> </del>	\$1001L	<del> </del>	<del> </del>		1.6	1.0	100	1	10	.01	0.2	0.5	1.6	1.5	0.2	<del></del>
Amps		S2001L		<b></b>		1.6	1.0	200	1	10	.01	0.2	0.5	1.6	1.5	0.2	
типро		S4001L				1.6	1.0	400	1	10	.01	0.2	0.5	1.6	1.5	0.2	<u> </u>
		S6001L				1,6	1.0	600	1	10	.01	0.2	0.5	1.6	1.5	0.2	
		S0303L				3.0	1.9	30	1	10	.01	0.2	0.5	1.6	1.5	0.2	
į		\$0503L				3.0	1.9	50	1	10	,01	0.2	0.5	1.6	1.5	0.2	
3		\$1003L				3.0	1.9	100	1	10	.01	0.2	0.5	1.6	1.5	0.2	
Amps		\$2003L				3.0	1,9	200	1	10	.01	0.2	0.5	1.6	1.5	0.2	
*		\$4003L				3.0	1.9	400	.1	10	.01	0.2	0.5	1.6	1.5	0.2	
		\$6003L	<u> </u>			3.0	1.9	600	1	10	.01	0.2	0.5	1.6	1,5	0.2	
			S0304F1	S0304N1		4.0	2.5	30	1_	10	.01	0.2	0.5	1.6	1.5	0.2	<u> </u>
			S0504F1	S0504N1	3	4.0	2.5	50	1	10	.01	0.2	0.5	1.6	1.5	0.2	ļ
4		-	\$1004F1	\$1004N1	· · · · · · · · · · · · · · · · · · ·	4.0	2.5	100	1	10	.01	0.2	0.5	1.6	1.5	0.2	<b></b>
Amps			\$2004F1	\$2004N1 \$4004N1		4.0	2.5	200	1	10	.01	0.2	0.5	1.6	1.5	0.2	<b></b>
	<del> </del>		\$4004F1 \$6004F1	\$6004N1		4.0	2.5	400 600	1	10 10	.01	0.2	0.5	1.6 1.6	1.5	0.2	<b> </b>
		S0306L	\$0306F1	30004111	<b> </b>	6.0	3.8	30	1	15	.01	0.2	0.5 0.5	1.6	1.5 1.5	0.2	<u> </u>
		S0506L	S0506F1			6.0	3.8	.50	1	15	.01	0.2	0.5	1.6	1.5	0.2	
6		\$1006L	S1006F1			6.0	3.8	100	1	15	.01	0.2	0.5	1.6	1.5	0.2	
Amps	<del></del>	S2006L	S2006F1			6.0	3.8	200	1	15	.01	0.2	0.5	1.6	1,5	0.2	
•		S4006L	S4006F1			6.0	3.8	400	1	15	.01	0.2	0.5	1.6	1.5	0,2	
		\$6006L	\$6006F1			6.0	3.8	600	1	15	.01	0.2	0.5	1.6	1,5	0,2	
1		\$0308L	S0308F1		S0308R	8.0	5.1	30	1	15	.01	0.2	0.5	1.6	1.5	0.2	
Ì		S0508L	S0508F1		S0508R	8.0	5.1	50	1	15	.01	0.2	0.5	1.6	1.5	0.2	
		S1008L	S1008F1		\$1008R	8.0	5.1	100	1	15	.01	0.2	0.5	1.6	1.5	0.2	
ı	<b> </b>	S2008L	S2008F1	ļ	S2008R	8.0	5.1	200	1	15	.01	0.2	0.5	1.6	1.5	0.2	<u></u>
8		\$4008L	\$4008F1		\$4008R	8.0	5.1	400	1	15	.01	0.2	0.5	1.6	1.5	0.2	
Amps	<del></del>	S6008L	S6008F1		S6008R	8.0	5.1	600	1	15	.01	0.2	0.5	1.6	1.5	0.2	
po	<del>                                     </del>		ļ		C122F	8.0	5.1	50		25	0.1	0.5	<del> </del>	1.83	1.5	0.2	
	<b></b>		<del> </del>		C122A C122B	8.0 8.0	5.1 5.1	100 200	ļ	25 25	0.1	0.5 0.5	ļ	1.83 1.83	1.5 1.5	0.2	
	<del></del>				C1226	8.0	5.1	300		25	0.1	0.5		1.83	1.5	0.2	
	<del> </del>		<del> </del>	<b></b> -	C122D	8.0	5.1	400		25	0.1	0.5	<del>                                     </del>	1.83	1.5	0.2	
ı				1	C122E	8.0	5.1	500	<del>                                     </del>	25	0.1	0.5		1.83	1.5	0.2	<del> </del>
			· ·		C122M	8.0	5.1	600		25	0.1	0.5	1	1.83	1.5	0.2	
<del></del>			<del> </del>												L		

#### **GENERAL NOTES**

- Teccor's 2N6394 Series, 2N6400 Series, and 2N6504 Series devices conform to all JEDEC registered data.
- · All measurements are made at 60 Hz with a resistive load at an ambient temperature of + 25°C unless otherwise specified.
- Operating temperature range (TJ) is -65°C to +125°C for TO-92 devices, 0°C to +125°C for Fastpak, and -40°C to +125°C for all other packages.
- Storage temperature range (TS) is  $-65^{\circ}$ C to  $+150^{\circ}$ C for TO-92 devices.  $-40^{\circ}$ C to  $+150^{\circ}$ C for TO-202 and TO-220 devices.  $-20^{\circ}$ C to  $+125^{\circ}$ C for Fastpak and  $-40^{\circ}$ C to  $+125^{\circ}$ C for all others
- Lead solder temperature is a maximum of 230°C for 10 seconds maximum; 1/16" from case.
- The case temperature (TC) is measured as shown on dimensional outline drawings. See "package dimensions" section of catalog.

# DE | 8872819 0001040 2 | 5 T-25-01 Electrical Specifications

	3 JH	IGM	PGM	PG(AV)	lΤε	SM	dv	/dt	2t	di/dt	tgt	tq
	DC Holding Current Gate Open (5) (14)	Peak Gate Current (11)	Peak Gate Power Dissipation (11)	Average Gate Power Dissipation	Cycle Forward (6)	One Surge Current (10)	of Ar Forward	al Rate oplied Voltage	RMS Surge (Non-Repetitive) On-State Current For a Period of 8.3 msec for Fusing	Maximum Rate of Rise of On-State Current IGT = 150mA With 0.1µs Rise Time	Gate Controlled Turn-On Time Gate Pulse = 100mA M.n. Width = $5\mu$ s With Rise Time $\leq 0.1\mu$ s (7)	Circuit Commutated Turn-Off Time (9) (10)
•	mA	Amps	Watts	Watts	60Hz	50Hz	TC = 100°C	TC = 125°C	Amps <sup>2</sup> sec	Amps/µs	μS	μ\$
	MAX	MAX			MAX	MAX	MIN	MIN			MAX	MAX
	20	1.5	15	0.3	30	25	40	30	3.7	50	2.0	35
•	20	1.5	15	0.3	30	25	40	30	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	40	30	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	40	30	3.7	50	2.0	35
	20 .	1.5	15	0.3	30	25	30	20	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	30	20	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	40	30	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	40	30	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	40	30	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	40	30	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	30	20	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	30	20	3.7	50	2.0	35
	20 -	1.5	15	0.3	30	25	40	30	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	40	30	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	40	30	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	40	30	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	30	20	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	30	20	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	40	30	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	40	30	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	40	30	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	40	30	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	30	20	3.7	50	2.0	35
	20	1.5	15	0.3	30	25	30	20	3.7	50	2.0	35
	30	2.0	20	0.5	100	60	175	125	41	100	2.0	35
	30	2.0	20	0.5	100	60	175	125	41	100	2.0	35
	30	2.0	20	0.5	100	60	175	125	41	100	2.0	35
	30	2.0	20	- 0.5	100	60	175	125	41	100	2.0	35
	30	2.0	20	0.5	100	60	175	125	41	100	2.0	35
	30	2.0	20	0.5	100	60	150	100	41	100	2.0	35
	30 30	2.0 2.0	20	0.5 0.5	100	60	175 175	125 125	41	100	2.0	35
	30	2.0	20	0.5	100 100	60 60	175	125	41 41	100 100	2.0	35 35
	30	2.0	20	0.5	100	60	175	125	41	100	2.0	35
	30	2.0	20	0.5	100	60	175	125	41	100	2.0	35
	30	2.0	20	0.5	100	60	150	100	41	100	2.0	35
	30	2.0	5	0.5	90	82	100	100	34	100	2.0	
	30	2.0	5	0.5	90	82	ļ	<del> </del>	34	100		
	30	2.0	5	· 0.5	90	82	<del> </del>	<del>  </del>	34	100		
	30	2.0	5	0.5	90	82			34	100	<b> </b>	
	30	2.0	5	0.5	90	82			34	100		
	30	2.0	5	0.5	90	82	<del> </del>		34	100		
	30	2.0	5	0.5	90	82	<del> </del>		34	100	<b> </b>	
	L		<u> </u>	i	1 00		1	1	<b>∀</b> 1	1 100	1	

NOTES TO ELECTRICAL SPECIFICATIONS

- (9) Test conditions are as follows: iT=1 amp for  $\leq 1.6$  amp devices and 2 amp for  $\geq 3$  amp devices. Pulse duration  $=50\mu$ sec.  $dv/dt=20 V/\mu s$ . di/dt=-10 amps $i\mu s$  for
- $\leq$  16 amp devices, and -30 amps/ $_{I}$ s for  $\geq$  3 amp devices  $^{1}$ GT = 200 mA @ turn-on (10) See Figure 2 (A.B.C.D.E) for maximum allowable case temperatures @ maximum rated current.
- (11) Pulse width  $\leq 3\mu$ s.

- (12) GT = 40 mA maximum @  $-40^{\circ}C$  for C122 devices (13) VGT = 2.0 V maximum @  $-40^{\circ}C$  for C122 devices. (14) Initial on-state current = 200 mA (DC) for 1 to 20 amp devices 400 mA (DC) for 25 to 70 amp devices.

<sup>(1)</sup> See Figures 2 and 3 for current rating at specified operating case temperature.

<sup>(2)</sup> See Figure 1 for free air current rating.

<sup>(3)</sup> See Figure 6 for instantaneous on-state current vs on-state voltage (typical).

<sup>(4)</sup> See Figure 5 for IGT vs\_TC.

<sup>(5)</sup> See Figure 4 for IH vs TC.

<sup>(6)</sup> For more than one full cycle rating, see Figure 9.

<sup>(7)</sup> See Figure 8 for tgt vs IGT. (8) See Figure 7 for VGT vs TC.

# TECCOR ELECTRONICS INC 73 DE BAB72AL9 000L04L 4 ) T-25-01 SCR's—Non Sensitive Gate

		Part Number		-1		VDRM &	lg	T	Inni	N & IR	RM	VTM	٧c	iT	
	Isolated	Non-Is	olated		•	VRRM			P(II	,, <u>se</u> 11					
ТҮРЕ	0	- O A	Ô	Maxii On-S Curi (*	State rent 1)	Repetitive Peak Off-State Forward & Reverse Voltage	Gate-1 Cur VD = RL =	C frigger rent 12 VDC : 60Ω 4)	Forw	eak Off-Stat rard & Reve Current @ RM & VRR	erse	Peak On-State Voltage at Max Rated RMS Current TC = 25°C (3)	DC Gate-Trigger Voltage VD = 12 VDC RL = 60Ω (8)  Volts		
	к∭ д	к	κ∭G	An	1ps					mA					1
ļ	TO-220AB	TO-292AB	NON-ISOLATED TO-220AB	IT(RMS)	lT(AV)	Volts	п	ıA	T <sub>C =</sub> 25°C	T <sub>C =</sub> 100°C	T <sub>C =</sub> 125°C	Volts	T <sub>C =</sub> 25°C	T <sub>C =</sub> 125°C	
	FOR DIMENSIONAL (	DUTLINES & PACKAGE VAR	IATIONS SEE PAGE 67	MAX	MAX	MIN	MIN	MAX	ļ	MAXIMUN	l 	MAX	MAX	MIN	
	\$0310L	S0310F1		10	6.4	30	1	15	.01	0.2	0.5	1.6	1.5	0.2	Ĺ
	S0510L	S0510F1	-	10	6.4	50	1	15	.01	0.2	0.5	1.6	1.5	0.2	ļ
	\$1010L	\$1010F1		10	6.4	100	1	15	.01	0.2	0.5	1.6	1.5	0.2	<b> </b> -
	\$2010L	S2010F1		10	6.4	200	1	15	.01	0.2	0.5	1.6	1.5	0.2	<del></del>
	S4010L	\$4010F1		10	6.4	400	1 1	15	.01	0.2	0.5	1.6	1.5	0.2	<del> </del>
10	\$6010L	S6010F1		. 10	6.4	600	1	15	.01	0.2	0.5	1.6	1.5	0.2	<b> </b>
Amps	L	<b></b>	S2800F	10	6.4	50	<del> </del>	15	<u> </u>	2.0 2.0	<b> </b>	2.0* 2.0*	1.5 1.5		<b></b>
			\$2800A	10	6.4	100	┨	15			<b> </b>	2.0*	1.5		<del> </del>
	<u></u>		\$2800B	10	6.4	200	<del> </del>	15		2.0		2.0*	1.5	<del></del>	<del> </del>
			\$2800C	10	6.4	300 400	<del> </del>	15 15		2.0	<del> </del>	2.0*	1,5	<del> </del>	<del> </del>
-			\$2800D	10	6.4	500	├	15		2.0		2.0*	1.5	<del> </del>	<del>                                     </del>
			\$2800E	10	6.4	600 -	╂	15		2.0	<del> </del>	2.0*	1.5	<del> </del>	
	000/01	<u> </u>	\$2800M	12	7.6	30	1	20	.01	0.5	1.0	1.6	1.5	0.2	<del>                                     </del>
	S0312L S0512L		S0312R S0512R	12	7.6	50	1 1	20	.01	0.5	1.0	1.6	1.5	0.2	
	\$1012L	<del> </del>	\$1012R	12	7.6	100	11	20	.01	0.5	1.0	1.6	1.5	0.2	<u> </u>
40	\$2012L	<del></del>	\$2012R	12	7.6	200	1	20	.01	0.5	1.0	1.6	1.5	0.2	
12	\$4012L		\$4012R	12	7.6	400	1	20	.01	0.5	1.0	1.6	1.5	0.2	
Amps	\$6012L		\$6012R	12	7.6	600	1	20	,01	0.5	1.0	1.6	1.5	0.2	
	000122		2N6394	12	7.6	50	1	30	.01		2.0	2.2	1.5	0.2	
		- <del></del>	2N6395	12	7.6	100		30	.01		2.0	2.2	1.5	0.2	
i			2N6396	12	7.6	200		30	.01		2.0	2.2	1.5	0.2	<u> </u>
			2N6397	12	7.6	400		30	.01	<u> </u>	2.0	2.2	1.5	0.2	ļ
			2N6398	12	7.6	600		30	.01		2.0	2.2	1.5	0.2	<u> </u>
l	\$0315L			15	9.5	30	1	30	.01	0.5	1.0	1.6	1.5	0.2	ļ
	\$0515L			15	9.5	50	11	30	.01	0.5	1.0	1.6	1.5	0.2	<del> </del>
15	S1015L			15	9,5	100	11	30	.01	0.5	1.0	1.6	1.5	0.2	<del> </del>
Amps	S2015L			15	9.5	200	11	30	.01	0.5	1.0	1.6	1.5	0.2	ļ
	S4015L		· -	15	9.5	400	1 1	30	.01	0.5	1.0	1.6	1.5	0.2	<del> </del>
	\$6015L			15	9.5	600	1	30	.01	0.5	1.0	1.6	1.5	0.2	<del> </del>
			S0316R	16	10	30	11	30	.01	0,5	1.0	1.6	1.5	0.2	╁
		<del>                                     </del>	S0516R	16	10	50 100	1 1	30	.01 .01	0.5 0.5	1.0	1.6	1.5	0.2	<del>                                     </del>
		<del>                                     </del>	\$1016R	16 16	10	200	1 1	30	.01	0.5	1.0	1.6	1.5	0.2	1
16		-	\$2016R \$4016R	16	10	400	++	30	.01	0.5	1.0	1.6	1.5	0.2	1
Amps	<del> </del>	1	\$6016R	16	10	600	1 1	30	.01	0.5	1.0	1.6	1.5	0.2	T
1		<del> </del>	2N6400	16	10	50	†- <u>`</u>	30	.01	1	2.0	1.7	1.5	0.2	
	<del> </del>	-	2N6401	16	10	100	1	30	.01		2.0	1.7,	1.5	0.2	
		<del> </del>	2N6402	16	10	200	1	30	.01	1	2.0	1.7	1.5	0.2	
		<del> </del>	2N6403	16	10	400	1	30	.01	1	2.0	1.7_	1.5	0.2	
		1	2N6404	16	10	600	7	30	.01		2.0	1.7	1.5	0.2	
	\$0320L		1	20	13	30	1	30	.01	0.5	1.0	1.6	1.5	0.2	
	S0520L			20	13	50	1	30	.01	0.5	1.0	1.6	1.5	0,2	<b></b>
_ 20	S1020L		-	20	13	100	1	30	.01	0.5	1.0	1.6	1.5	0.2	
Amps	\$2020L	-		20	13	200	1	30	.01	0.5	1.0	1.6	1.5	0.2	<del> </del>
ļ	\$4020L			20	13	400	1	30	.01	0.5	1.0	1.6	1.5	0.2	<del> </del>
1	\$6020L			20	13	600	1	30	.01	0.5	1.0	1.6	1.5	0.2	

\*VTM @ iT = 30Apk

## **GENERAL NOTES**

- Teccor's 2N6394 Series, 2N6400 Series, and 2N6504 Series devices conform to all JEDEC registered data.
- · All measurements are made at 60 Hz with a resistive load at an ambient temperature of + 25°C unless otherwise specified.
- Operating temperature range (TJ) is 65°C to + 125°C for T0-92 devices, 0°C to + 125°C for Fastpak, and 40°C to + 125°C for all other packages.
   Storage temperature range (TS) is -65°C to + 150°C for T0-92 devices, -40°C to + 150°C for T0-202 and T0-220 devices, -20°C to + 125°C for Fastpaks and -40°C to + 125°C
- Lead solder temperature is a maximum of 230°C for 10 seconds maximum; 1/16" from case.
- The case temperature (TC) is measured as shown on dimensional outline drawings. See "package dimensions" section of catalog.

#### NOTES FOR JEDEC DEVICES

- 1. 2N6400-6405 series of devices also conform to the following speci-fications a Maximum VGT = 2.5 volts @  $-40^{\circ}$ C

  - b. Maximum IH = 60 milliamps @ -40°C
- 2. 2N6504-6508 series of devices also conform to the following specifications: a. Maximum VGT = 1.5 volts @  $-40^{\circ}\text{C}$  b. Maximum IGT = 75 milliamps @  $-40^{\circ}\text{C}$  c. Maximum IH = 40 milliamps @  $-40^{\circ}\text{C}$

## Electrical Specifications

·						3 1		1	40			
	i li	IGM	PGM	PG(AV)	ITS	М	_ ďv/	dt.	121	di/dt	. <sup>t</sup> gt	tq
-	DC Holding Current Gate Open (5) (14)	Peak Gate Current (11)	Peak Gate Power Dissipation (11)	Average Gate Power Dissipation	Peak Cycle S Forward (6) (	Gurge Current	Critical of Ap Forward	plied	RMS Surge (Non-Repetitive) On-State Current For a Period of 8.3 msec for Fusing	Maximum Rate of Change of On-State Current IGT = 150mA With 0.1µs Rise Time	Gate Controlled Turn-On Time Gate Pulse = 100mA Min. Width = 5µs With Rise Time ≤ 0.1µs	Circuit Commutated Turn-Off Time (9) (10)
·					Am	ps	Volt	slμS		nise tillle	(7)	
	mA	Amps	Watts	Watts	60Hz	50Hz	TC = 100°C	TC = 125°C	Amps <sup>2</sup> sec	Amps/μs	μ\$	μ\$
	MAX	,			MAX	MAX	MIN	MIN			MAX	MAX
	30	2.0	20	0.5	100	83	175	125	41	100	2.0	35
	30	2.0	20	0.5	100	83	175	125	41	100	2.0	35
	30	2.0	20	0.5	100	83	175	125	41	100	2.0	35
	30	2.0	20	0.5	100	83	175	125	41	100	2.0	35
<del>' '</del>	30	2.0	20	0.5	100	83	175	125	41	100	2.0	35
<del></del>	30	2.0	20	0.5	100	83	150	100	41	190	2.0	35
<del> </del>	20		20	Ò.5	100	85	100		40	100	2.5	35
			20	0.5	100	85	75		40	100	2.5	35
	20		20	0.5	100	85	50	,	40	100	2.5	35
-	20		20	0.5	100	85	40		40	100	2.5	35
<u> </u>	20		20	0.5	100	85	30		40	100	2.5	35
ļ	20			0.5	100	85	25	l	40	100	2.5	35
<u> </u>	20		20 -		100	85	20	<u> </u>	40	100	2.5	35
	20		20	0.5				125	60	100	2.0	35
	40	2.0	20	0.5	120	100	175	125	60	100	2.0	35
	40	2.0	20	0.5	120	100	175		60	100	2.0	35
<u> </u>	40	2.0	20	0.5	120	100	175	125		100	2.0	35
L	40	2.0	20	0.5	120	100	175	125	60			35
Ī	40	2.0	20	0.5	120	100	175	125	60	100	2.0	35
	40	2.0	20	0.5	120	100	150	100	60	100	2,0	30
i .	40	2.0	20	0.5	100		<u>                                     </u>	<u> </u>	40	100	2.0	ļ
	40	2.0	20	0.5	100			ļ	40	100	2,0	<u> </u>
	40	2.0	20	0.5	100	<u> </u>	ļ		40	100	2.0	ļ
	40	2.0	20	0.5	100				40	100	2.0	<b> </b>
	40	2.0	20	0.5	100				40	100	2.0	<u> </u>
<del> </del>	40	3.0	30	0.6	225	188	250	175	210	125	2.0	35
-	40	3.0	30	0.6	225	188	250	175	210	125	2.0	35
-	40	3,0	30	0.6	225	188	250	175	210	125	2.0	35
	40	3.0	30	0.6	225	188	250	175	210	125	2,0	35
-		3.0	30	0.6	225	188	250	175	210	125	2.0	35
<del></del>	40	3.0	30	0.6	225	188	200	150	210	125	2.0	35
<u> </u>	40			0.6	225	188	250	175	210	125	2.0	35
-	40	3.0	30	0.6	225	188	250	175	210	125	2.0	35
<u> </u>	40	3.0	30	0.6	225	188	250	175	210	125	2.0	35
	40	3.0		0.6	225	188	250	175	210	125	2.0	35
-	40	3.0	30	0.6	225	188	250	175	210	125	2.0	35
	40	3.0	30		225	188	200	150	210	125	2.0	35
-	40	3.0	30	0.6		100	200	1-100	100	125	1	
ļ	40	2.0	20	0.5	160	+	+	<del> </del>	100	125		T
	40	2.0	20	0.5	160	<del>                                     </del>	+	┼		125	<del> </del>	<del> </del>
	40	2.0	20	0.5	160	<del> </del>	<del></del>	+	100	125	<del> </del>	+
L	40	2.0	20	0.5	160	<del> </del>	<del></del>	+	100	125		<del> </del>
	40	2.0	20	0.5	160				100		<del>                                     </del>	75
	40	3,0	30	0.6	300	255	250	175	374	125	2.0	35 35
	40	3.0	30	0.6	300	255	250	175	374	125	2.0	
	40	3.0	30	0.6	300	255	250	175	374	125	2.0	35
	40	3.0	30	0.6	300	255	250	175	374	125	2.0	35
	40	3.0	30	0.6	300	255	250	175	374	125	2.0	35
	40	3.0	30	0.6	300	255	200	150	374	125	2.0	35

#### NOTES TO ELECTRICAL SPECIFICATIONS

- (1) See Figures 2 and 3 for current rating at specified operating case temperature.
  (2) See Figure 1 for free air current rating.
  (3) See Figure 6 for instantaneous on-state current vs on-state voltage (typical).
  (4) See Figure 5 for IGT vs TC.
  (5) See Figure 4 for IH vs TC.
  (6) For more than one full cycle rating, see Figure 9.
  (7) See Figure 8 for 1gt vs IGT.
  (8) See Figure 7 for VGT vs TC.

- (9) Test conditions are as follows: iT = 1 amp for ≤ 1.6 amp devices and 2 amp for ≥ 3 amp devices. Pulse duration = 50μsec. dv/dt = 20 V/μs, di/dt = −10 amps/μs for ≤ 1.6 amp devices. and −30 amps/μs for ≥ 3 amp devices. IGT = 200 mA @ turn-on.
- (10) See Figure 2 (A,B,C,D,E) for maximum allowable case temperatures @ maximum rated current.
- (11) Pulse width  $\leq 3\mu$ S.
- (12)  $|GT = 40 \text{ mA maximum } @ -40^{\circ}C \text{ for C122 devices.}$ (13)  $|VGT = 2.0 \text{ V maximum } @ -40^{\circ}C \text{ for C122 devices.}$
- (14) Initial on-state current = 200 mA (DC) for 1 to 20 amp devices. 400 mA (DC) for 25 to 70 amp devices.

· .	Part Number Isolated Non-Isolated						Т	VDRM & VRRM	Ig	ìT **	IDR	M & IF	RRM	VTM	V(	aT .	
TYPE	0			, O J	A O	Maxi On-S Curr (1	State rent 1}	Repetitive Peak Off-State Forward & Reverse Voltage	Cur VD = RL =	C rigger rent 12 VDC : 60Ω 4)	Forv	eak Off-Stat vard & Rev Current @ DRM & VRR	erse	Peak On-State Voltage at Max Rated RMS Current TC = 25°C (3)	Vo ≃	age 12 VDC : 60Ω 3)	
,	K∭G A	KAG	FASTPAK TO-3 Base	A Non-isolated	K A G NON-ISOLATED TO-218	I <sub>T(RMS)</sub>	I <sub>T(AV)</sub>	Volts		ıA	T <sub>C =</sub> 25°C	mA T <sub>C =</sub> 100°C	T <sub>C =</sub>	Volts	T <sub>C =</sub> 25°C	T <sub>C =</sub> 125°C	
	TO-220AB FOR DIMEN	T0-218 ISIONAL OUTLIN	VES & PACKAGE	TO-220A8  VARIATIONS SE	L	MAX	MAX	MIN	MIN	MAX	<u> </u>	MAXIMUN		MAX	MAX	MIN	
	S0325L	1		\$0325R		25	16	30	1	30	.01	1.0	2.0	1.6	1.5	0.2	<u> </u>
	S0525L		<u> </u>	S0525R		25	16	50	1	30	.01	1.0	2.0	1.6	1.5	0.2	
•	\$1025L		<b></b>	\$1025R	-	25	16	100	1	30	.01	1.0	2.0	1.6	1.5	0.2	
•	S2025L			S2025R		25	16	200	1	30	.01	1.0	2.0	1.6	1.5	0.2	
	S4025L			S4025R		25	16	400	1	30	,01	1.0	2.0	1.6	1.5	0.2	
25	\$6025L		1	S6025R		25	16	600	1	30	.01	1.0	2,0	1.6	1.5	0.2	
Amps				2N6504		25	16	50		40	.01		2.0	1.8		0.2	
				2N6505		25	16	100		40	.01		2.0	1.8		0,2	
				2N6506		25	16	200		40	.01		2.0	1.8		0.2	
				2N6507		25	16	400		40	.01		2,0	1.8		0.2	
			<u> </u>	2N6508		25	16	600		40	.01		2.0	1.8	L	0.2	
		S0335J			S0335W	35	22	30	5	40	.01	1.0	2.0	1.8	1.5	0.2	ļ
		S0535J			S0535W	35	22	50	5	40	.01	1.0	2.0	1.8	1.5	0.2	ļ
35		S1035J	ļ		S1035W	35	22	100	5	40	.01	1.0	2.0	1.8	1.5	0.2	ļ
Amps		\$2035J			\$2035W	35	22	-200	5	40	.01	1.0	2.0	1.8	1.5	0.2	<b></b>
	<u> </u>	\$4035J	ļ	·	\$4035W	35	22	400	5	40	.01	1.0	2.0	1,8	1.5 1.5	0.2	<del>                                     </del>
	<u> </u>	\$6035J			S6035W	35	22	600 50	5	40	.01	1.0		1.8	1.5	0.2	├
	<b></b>	\$0550J \$1050J	<b> </b>		ļ	50 50	32	100	5	40	.01 .01	1.0	2.0	1.8	1.5	0.2	<del> </del>
50	<del>                                     </del>	\$2050J	<u> </u>			50	32	200	5	40	.01	1.0	2.0	1.8	1.5	0.2	$\vdash$
Amps		\$4050J				50	32	400	5	40	.01	1.0	2.0	1.8	1.5	0.2	
	ļ	S6050J	<del>                                     </del>		<b></b>	50	32	600	5	40	.01	1.0	2.0	1.8	1.5	0.2	
	<del> </del>	000000	<del> </del>	<del> </del>	S0555W	55	35	50	5	40	.01	1.0	2.0	1.8	1,5	0.2	<del> </del>
			<del> </del>		S1055W	55	35	100	5	40	.01	1.0	2.0	1.8	1.5	0.2	<del> </del>
55	<del>                                     </del>	<del> </del>	<del> </del>		S2055W	55	35	200	5	40	.01	1.0	2.0	1.8	1.5	0.2	
Amps	†				\$4055W	55	35	400	5	40	.01	1.0	2,0	1.8	1.5	0.2	Γ
	<u> </u>		1		\$6055W ^	55	35	600	5	40	.01	1.0	2.0	1.8	1.5	0.2	
			S0565P			65	41	50	5	50	.02	1.5	3.0	1.8	2.0	0.2	
			\$1065P	-		65	41	100	5	50	.02	1.5	3.0	1.8	2.0	0.2	
	<u></u>		S2065P			65	41	200	5	50	.02	1.5	3.0	1.8	2.0	0.2	<u> </u>
	<u> </u>	<b> </b>	S4065P			65	41	400	5	50	.02	1.5	3.0	1.8	2.0	0.2	<u> </u>
65	<b> </b>	1-2-2-2	S6065P			65	41	600	5	50	.02	1.5	3.0	1.8	2.0	0.2	<u> </u>
Amps	<b> </b>	\$0565J	ļ		ļ	65	41	50	5	50	.02	1.5	3.0	1.8	2.0	0.2	<del> </del>
	<b></b>	\$1065J	<del> </del>			65	41	100	5	50	.02	1.5	3.0	1.8	2.0	0.2	<del> </del>
	<del> </del>	\$2065J	<del> </del>			65 65	41	200	5	50 50	.02	1.5 1.5	3.0	1.8	2.0	0.2	<del> </del>
	<del> </del>	\$4065J \$6065J	<del> </del>	<del> </del>	<b></b>	65	41	400 600	5	50	.02	1.5	3.0	1.8	2.0	0.2	<del>                                     </del>
	<del> </del>	300000	<del> </del>	<del> </del>	S0570W	70	45	50	5	50	.02	1.5	3.0	1.8	2.0	0.2	-
	<del> </del>	<del> </del>	<del> </del>	<del> </del>	\$1070W	70	45	100	5	50	.02	1.5	3.0	1.8	2.0	0.2	
70	+		+	<u> </u>	S2070W	70	45	200	5	50	.02	1.5	3.0	1.8	2.0	0.2	<del>                                     </del>
Amps	<del> </del>	<del>                                     </del>	<del> </del>		\$4070W	70	45	400	5	50	.02	1.5	3.0	1.8	2.0	0.2	<del> </del>
	<b>†</b>	<del> </del>	<del> </del>	<del> </del>	\$6070W	70	45	600	5	50	.02	1.5	3.0	1.8	2.0	0.2	<b>T</b>
		.1	1	1				4							<del> </del>		

#### **GENERAL NOTES**

- Teccor's 2N6394 Series, 2N6400 Series, and 2N6504 Series devices conform to all JEDEC registered data.
- · All measurements are made at 60 Hz with a resistive load at an ambient temperature of + 25°C unless otherwise specified.
- Operating temperature range (TJ) is -65°C to +125°C for T0-92 devices. 0°C to +125°C for Fastpak, and -40°C to +125°C for all other packages.
   Storage temperature range (TS) is -65°C to +150°C for T0-92 devices. -40°C to +150°C for T0-202 and T0-220 devices. -20°C to +125°C for Fastpaks. and -40°C to +125°C
- Lead solder temperature is a maximum of 230°C for 10 seconds maximum; 1/16" from case.
- The case temperature (<sup>TC</sup>) is measured as shown on dimensional outline drawings. See "package dimensions" section of catalog.

#### NOTES FOR JEDEC DEVICES

- 1. 2N6400-6405 series of devices also conform to the following specifications a. Maximum VGT = 2.5 volts @  $-40^{\circ}$ C b Maximum IH = 60 milliamps @  $-40^{\circ}$ C
- 2. 2N6504-6508 series of devices also conform to the following specifications
  - a. Maximum VGT = 1.5 volts @  $-40^{\circ}$ C b. Maximum IGT = 75 milliamps @  $-40^{\circ}$ C c. Maximum IH = 40 milliamps @  $-40^{\circ}$ C

			<b>.</b>									
*	» JH	IGM	PGM	PG(AV)	.lŢ	SM	dv	/dt	2 <sub>1</sub>	di/dt	tgt	tq
L.	DC Holding Current Gate Open (5) (14)	Peak Gate Current (11)	Peak Gate Power Dissipation (11)	Average Gate Power Dissipation	Cycle Forward (6)	c One Surge I Current (10)		pplied Voltage	RMS Surge (Non-Repetitive) On-State Current For a Period of 8.3 msec for Fusing	Maximum Rate of Change of On-State Current IGT = 150mA With 0 1μs Rise Time	Gate Controlled Turn-On Time Gate Pulse = 150mA Min Width = $5\mu$ s With Rise Time $\leq 0.1\mu$ s	Circuit Commutated Turn-Off Time (9) (10)
				]	An	nps	Volt	<b>\$/</b> μS		Tado Timo	(7)	
	mA	Amps	Watts	Watts	60Hz	50Hz	TC = 100°C	TC = 125°C	Amps²sec	μ <b>\$</b>	μ\$	μ\$
-	MAX				MAX	MAX	MIN	MIN			MAX	MAX
	40	3.5	35	0.8	350	300	250	175	510	150	2.0	35
	40	3.5	35	0.8	350	300	250	175	510	150	2.0	35
	40	3.5	35	0.8	350	300	250	175	510	150	2.0	35
	40	3.5	35	0.8	350	300	250	175	510	150	2.0	- 35
	40	3.5	35	8,0	350	300	250	175	510	150	2.0	35
	40	3.5	35	0.8	350	300	200	150	510	150	2.0	35
		2.0	20	0.5	300	255			375	150	2.0	
	<u> </u>	2.0	20	0.5	300	255			375	150	2.0	
		2,0	20	0.5	- 300	255			375	150	2.0	
		2.0	20	0.5	300	255			375	150	2.0	
		2.0	20	0.5	300	255	ļ		375	150	2.0	
	50	3.5	35	0.8	500	425	250	175	1035	150	2.0	35
	50	3.5	35	0.8	500	425	250	175	1035	150	2.0	35
	50	3.5	35	0.8	500	425	250	175	1035	150	2.0	35
	50	3.5	35	0.8	500	425	250	175	1035	150	2.0	35
	50	3.5 3.5	35 35	0.8	500	425	250	175	1035	150	2.0	35
	50		40	0.8	500	425	200	150	1035	150	2.0	35
	50 50	4.0 4.0	40	0.8	650 650	550 550	425 425	300 300	1750 1750	175 175	2.5	35
	50	4.0	40	0.8	650	550	425	300	1750	175	2.5 2.5	35
	50	4.0	40	0.8	650	550	425	300	1750	175	2.5	35 35
	50	4.0	40	0.8	650	550	375	250	1750	175	2.5	35
	50	4.0	40	0.8	650	550	425	300	1750	175	2.5	35
	50	4.0	40	0.8	650	550	425	300	1750	175	2.5	35
	50	4.0	40	0.8	650	550	425	300	1750	175	2.5	35
	50	4.0	40	0.8	650	550	425	300	1750	175	2.5	35
	50	4.0	40	0.8	650	550	375	250	1750	175	2.5	35
	50	5.0	50	1.0	900	750	425	300	3360	200	2.5	35
	50	5.0	50	1.0	900	750	425	300	3360	200	2.5	35
	50	5.0	50	1.0	900	750	425	300	3360	200	2.5	35
	50	5.0	50	1.0	900	750	425	300	3360	200	2.5	35
	50	5.0	50	1.0	900	750	375	250	3360	200	2.5	35
	50	5.0	50	1.0	950	800	425	300	3745	200	2.5	35
	50	5.0	50	1.0 ·	950	800	425	300	3745	200	2.5	35
	50	5,0	50	1.0	950	800	425	300	3745	200	2,5	35
	50	5.0	50	1.0	950	800	425	300	3745	200	2.5	35
	50	5,0	50	1.0	950	800	375	250	3745	200	2.5	35
	50	5.0	50	1.0	950	800	425	300	. 3745	200	2.5	35
	50	5.0	50	1.0	950	800	425	300	3745	200	2.5	35
	50	5.0	50	1.0	950	800	425	300	3745	200	2.5	35
	50	5.0	50	1.0	950	800	425	300	3745	200	2.5	35
	50	5.0	50	1.0	950	800	375	250	3745	200	2.5	35

#### NOTES TO ELECTRICAL SPECIFICATIONS

- (1) See Figures 2 and 3 for current rating at specified operating case temperature.
  (2) See Figure 1 for free air current rating
  (3) See Figure 6 for instantaneous on-state current vs on-state voltage (typical)
  (4) See Figure 5 for IGT vs TC.
  (5) See Figure 4 for IH vs TC.
  (6) For more than one full cycle rating, see Figure 9.
  (7) See Figure 8 for 1gt vs IGT.
  (8) See Figure 7 for VGT vs TC.

- (9) Test conditions are as follows: iT = 1 amp for  $\leq 1.6$  amp devices and 2 amp for  $\geq$ 3 amp devices. Pulse duration =  $50\mu$ sec,  $dv/dt = 20 V/\mu$ s,  $dt/dt = -10 \text{ amps/}\mu\text{s}$  for  $\leq$  1.6 amp devices, and -30 amps/ $\mu$ s for  $\geq$  3 amp devices. IGT = 200 mA @ turn-on
- (10) See Figure 2 (A.B.C.D.E) for maximum allowable case temperatures @ maximum rated current.
- (11) Pulse width  $\leq 3\mu$ s.
- (12)  $^{\circ}$  IGT = 40 mA maximum @ -40°C for C122 devices. (13)  $^{\circ}$  VGT = 2.0 V maximum @ -40°C for C122 devices.
- (14) Initial on-state current = 200 mA (DC) for 1 to 20 amp devices. 400 mA (DC) for 25 to 70 amp devices.

		THERM	MAL RESI	STANCE (	STEADY ST	ATE)		
TYPE	PLASTIC TO-92	THERMOTAB TO-220AB	TYPE 1 TO-202	TYPE 2 TO-202	NON-ISOLATED TO-220AB	ISOLATED TO-218X	NON-ISOLATED TO-218X	FASTPAK TO-3 BASE
1.0 Amp	50/145						-	,
1.6 Amp		6.7						
3.0 Amp		6.3/50						
4.0 Amp			5.6/45	9.5/70				
6.0 Amp		4.0	4.3	-				
8.0 Amp		3.4	3.9		2.1/40			
10,0 Amp		3.0	3.4		1.9			
12.0 Amp		2.1			1.7			
15.0 Amp		1.95						
16.0 Amp					1.5			
20.0 Amp		1.8	-					
25 Amp		2.5			1.1			
35 Amp						.70	.50	
50 Amp						.80		
55 Amp							- ,53	
65 Amp						.86		.80
70 Amp		-					.60	

#### **ELECTRICAL ISOLATION**

Most Teccor isolated SCR packages will withstand a minimum high potential test of 2500 VAC RMS from leads to case over the device's operating temperature range. See table for standard and optional isolation ratings.

E	ELECTRICAL ISOLATION FROM LEADS TO CASE U.L. RECOGNIZED FILE #71639											
TYPE VAC (RMS)	TO-92	ISOLATED TO-220AB	ISOLATED TO-218	FASTPAK								
1600	Standard	_	-	_								
2500	No	Standard	Standard	Standard								
4000	No	Optional*	No	No								

<sup>\*</sup>For 4000V Isolation Use "V" Suffix

FIGURE 1A — Maximum Allowable Ambient Temperature vs RMS On-State Current

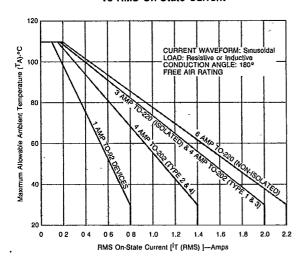


FIGURE 1B -- Maximum Allowable Ambient Temperature vs Average On-State Current

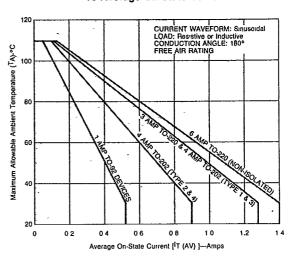


FIGURE 2A -- Maximum Allowable Case Temperature vs RMS On-State Current

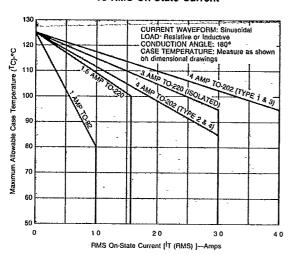


FIGURE 2B - Maximum Allowable Case Temperature vs RMS On-State Current

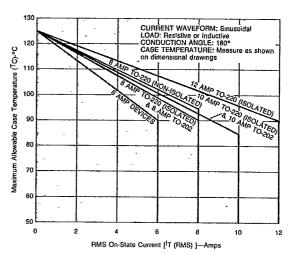


FIGURE 2C — Maximum Allowable Case Temperature vs RMS On-State Current

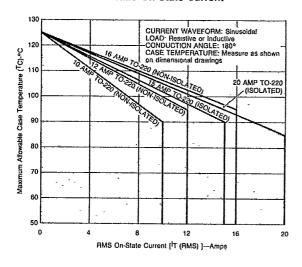


FIGURE 2D — Maximum Allowable Case Temperature vs RMS On-State Current

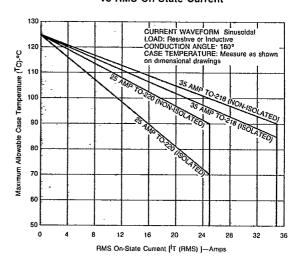


FIGURE 2E — Maximum Allowable Case Temperature vs RMS On-State Current

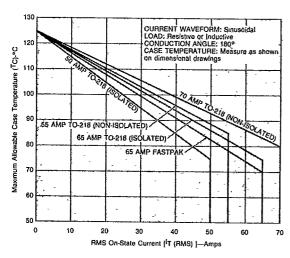


FIGURE 3A — Maximum Allowable Case Temperature vs Average On-State Current

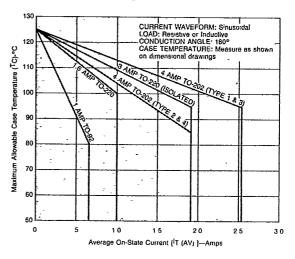


FIGURE 3B — Maximum Allowable Case Temperature vs Average On-State Current

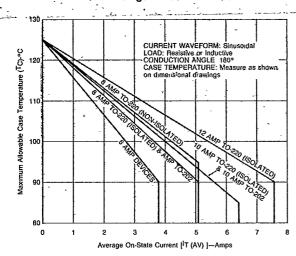


FIGURE 3C — Maximum Allowable Case Temperature vs Average On-State Current

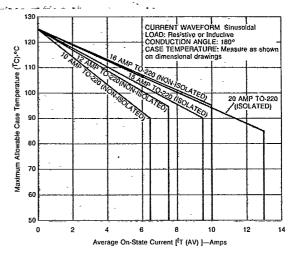


FIGURE 3D — Maximum Allowable Case Temperature vs Average On-State Current

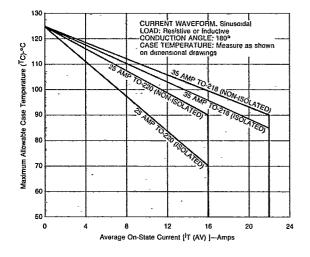


FIGURE 3E — Maximum Allowable Case Temperature vs Average On-State Current

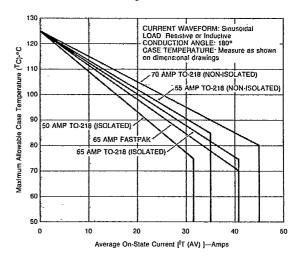


FIGURE 4 — Normalized DC Holding Current vs Case Temperature

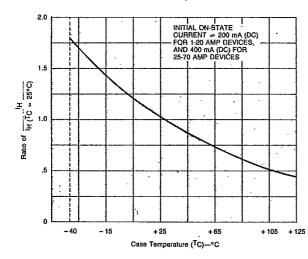
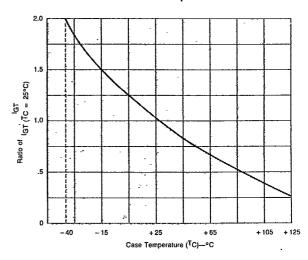


FIGURE 5 — Normalized DC Gate-Trigger Current vs Case Temperature



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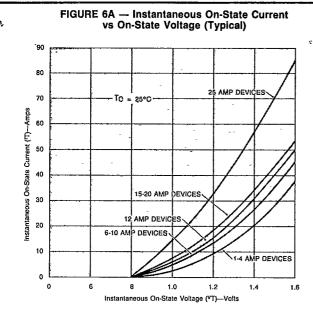


FIGURE 7 — Normalized DC Gate-Trigger Voltage vs Case Temperature

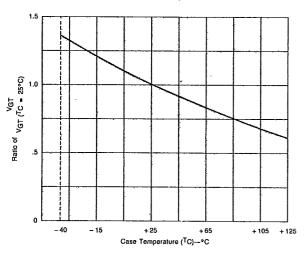


FIGURE 10A — Power Dissipation (Typical) vs RMS On-State Current

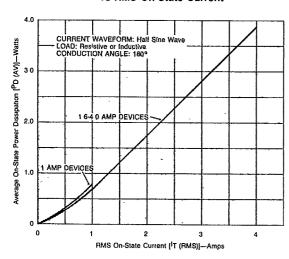


FIGURE 6B — Instantaneous On-State Current vs On-State Voltage (Typical)

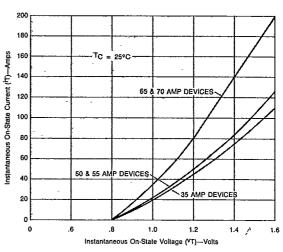


FIGURE 8 - Typical Turn-On Time vs Gate Trigger Current

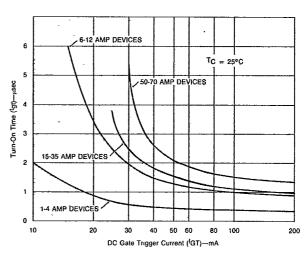
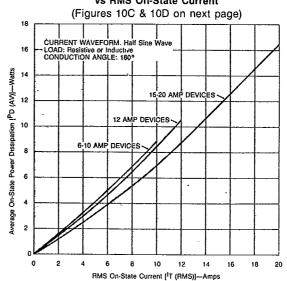


FIGURE 10B — Power Dissipation (Typical) vs RMS On-State Current



## FIGURE 9 — Peak Surge Current vs Surge Current Duration

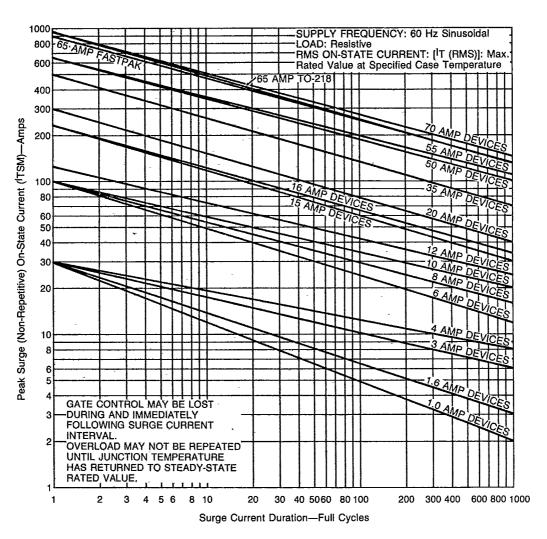


FIGURE 10C — Power Dissipation (Typical) vs RMS On-State Current

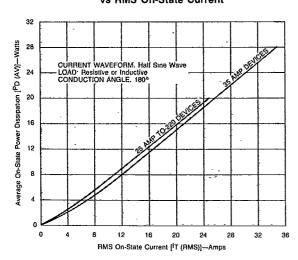


FIGURE 10D — Power Dissipation (Typical) vs RMS On-State Current

